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HX3078-S Bus Ransceiver Circuit

The HX3078-S is an RS485/RS-422 transceiver circuit equipped with a 3.3V/ 5V voltage supply, half-duplex communication, and ± 15 KV ESD protection. This circuitencompasses a driver and a receiver.

The HX3078-S showcases enhanced swing rate limits, which assist in minimizing output electromagnetic interference (EMI) and alleviating reflections caused by mismatched terminal connections, facilitating error-free data transfer rates of up to 500Mbps.

The receiver input impedance of the HX3078-S chip is 1/8 unit load, enabling the attachment of up to 256 transceivers for half-duplex communication on the bus. All driver outputs provide $\pm 15 kV$ human mode ESD protection. The chip is packaged in SOP8 and is capable of operating within a temperature range from -40 $^{\circ}$ C to +125 $^{\circ}$ C.



Peculiarity

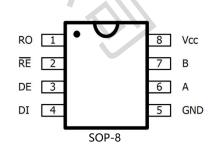
- 3.3V/5V supply voltage
- Electrostatic protection (ESD): A/B±15KV, in line with the human body mode (HBM) standard
- With 1/8 unit load, the bus allows up to 256 transceivers to be attached
- Supports error-free data transmission up to 500Mbps
- With Fail-safe function
- Adopt SOP8 packaging.

Apply

- Industrial control
- ammeter
- Industrial motor drive
- Isolated RS485 interface
- Automated heating, ventilation and air conditioning (HVAC) systems

	Chip Pin Description						
ID	NAME	FEATURE	INSTRUCTIONS				
1	RO	Receiver data output	When the receiver is enabled, after polarity judgment, the following conditions apply: - If V(A) - V(B) > -50mV, then the RO output is high If V(A) - V(B) < -200mV, then the RO output is low. Here, A and B represent the in-phase terminals of the chip post-polarity judgment.				
2	RE	Receiver output enable	When the receiver output is enabled, the RO output is effective if RE is connected to a low level; If RE is on a high level, the receiver will be turned off. At the same time, when RE is high and DE is low, the whole chip is turned off.				
3	DE	Driver output enable	When DE is high, the driver output is enabled. When DE is low, the driver turns off and the output enters a high resistance state. Additionally, when RE is high and DE is low, the entire chip is in an off state.				
4	DI	Drive driver data input	When the driver input DI is low level, the forced in-phase output is low level, and the reverse phase output is high level. When DI is high, the mandatory in-phase output is high, and the inverter output is low.				
5	GND	Ground	Ground				
6	Α	Driver data output receiver data input	In the bus interface, the in-phase output of the driver is connected to the in-phase input of the receiver.				
7	В	Driver data output receiver data input	In the bus interface, the inverting output of the driver is connected to the inverting input of the receiver.				
8	Vcc	Power source	Power source				

Drive truth table									
	Input	Exportation							
RE	DE)I	В		Α			
Х	1		1	0		1			
X	1	()	1		0			
0	0)	<	Z		Z			
1	0)	Κ	Shutoff					
	Re c eive r truth table								
	Inpi	ut				Exportation			
RE	DE	DE		A-B		RO			
0	X		≥-	50mV	1				
0	X		≤-2	200mV	0				
0	X	Х		hort circuit	1				
1	1	1		Х		Z			
1	0	0		X		Shutoff			



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		DC			al parar	neters							
SYMBOL	DΔ	DAME		III rai	ametei	MIN		MAX	1		111	VIT	
VCC				<u> </u>		3.0 +6.0				V			
DE, RE C	DE, RE Control input volt					-0.3 +6.0							
	DI Drive input volta					-0.3 +6.0					V		
A,B Drv Out/Rcv In						-8.0 +13.0					V		
						<u>-65</u>		+150			°C		
TOP Working PD SOF	ng te	mpera +Abov	2 70	rang ℃\	е	-40		+125 471			°C		
T _L Soldering	temr	r Abov peratu	re (10) seco	onds)			+300			°(
						± 5% , TA=25°C)	1 300					
PARAMETER	X		SYM	BOL	Te	est condition	1 S	MIN	T\	/P	MAX	U	INIT
						Driver				1			
Differential Drive Output (No Load	<u>t</u>		VO	D1	D F00	Figure 1	1	2					V
Differential drive output	不		VO	D2		Ω(RS-422) Fig Ω(RS-485) Fig		1.2 1.2				_	V V
Differential output amplitude variati	on 1		ΔVC	חר		Ω or R=27 Ω F		1,2			0.2		V
Driver output common mode level	0111		VC			Ω or R=27 Ω		0			3		V
Driver output common mode level val	iatio		ΔV		R=509	Ω or R=2 <u>7</u> Ω I	igure 1	-			0.2		V
Input High Level			VII			DE,DI, RE	2	2.0					V
Input low level			VI			DE,DI, <u>RE</u>					0.8		V
Input lag			VH			DE,DI,_RE			10	00			nV
Input Current				V 1	DE	DE,DI, RE 2					±2	ι	JΑ
Input current (A and B)			III	14			VIN=12V VIN=-7V	-75			125	- ι	AL
,			- 1			7V≤VOUT≤V		-100				r	nA
Driver output short-circuit curre	nt		101	D1		V≤VOUT≤12		100			100		nA
'						V≤VOUT≤V0		±25					nA
		•			Receive	er		•	•			•	
Receiver differential input threshold volta				VTH -7V≤VCM≤+12V			2V	-200	-		-50		nV
Receiver differential input threshold voltage	hyst	eresis		ΔVTH				-	4		-		nV
Receiver output high level		\(\circ\)		VOH IO=-4mA,VID=1V			1V	Vcc-0.4	-		-0		V
Receiver output low level "Receiver high impedance leakage curr	ent"	VOL IOZF	_	IO=4mA,VID=-1V 0.4V≤VO≤2.4V				0 -	-		<u>.4 ±</u> 1 ±	_	ıA
Receiver input impedance	CITE	RIN		-7V≤VCM≤+12V			_	96	-		ΙI		Ω
Receiver output short-circuit curren	t	IOSE		0V≤VRO≤VCC ±7 -						956		nA	
·		1031				upply curren	DE=VCC						
Static power supply current		ICC	No I	oad I	RE-DI-GI	NDorVcc [E=GND		45		006		ıA
1 11 3			1401	No load, RE=DI=GNDorVcc				45	0	00			
turn-off current	S	HDN		DE=GND, RE=Vcc 0.1 Static protection characteristics							10	u	ıA
Electrostatic protection				Contact discharge model +12									
(Pin A, Pin B)		ŀ						±15				K	(V
Electrostatic protection				manikin				+4				К	(V
Comm u n i	catio	n cha	r act	er is	tics (Vcc	=3.3V ± 5%,	TA=25 ℃						
PARAMETER				S١	YMBOL		CONDITIO			MIN		MAX	UNIT
Driver input/output delay					:DPLH		RDIFF=54			25	72	10	ns
					DPHL	CL= RDIFF=54 C	54pF Figur) F	25	72	10	
Difference in Input and Output Delay of Drive up and down time	of Dri	vers			OSKEW	RDIFF=54 C				40	-3 70	±1 12	ns ns
					DR,tDF				3,3	40		12	
maximum rate Enable the driver to output at a high	level				fMAX tDZH		<u>,S2 Turn off</u> ,S1 Turn off				_50	25	kb ns
Enable the driver to output at a low le					tDZL		31 Turn off F		7			25	ns
Drive from low output to shutdown time					tDLZ		S2 Turn off F					500	ns
Drive from high output to shutdown time					tDHZ							500	ns
Receiver input/output delay					RPLH		VID ≥	2.0V;			125	250	ns
programme and the second				t	RPHL	The VID's	rise and fa	all time, a	S	_	123		5
TRPLH tRPHL Receiver Input Output Delay Difference					RSKD	depicte d n Fi	,	•			10	±50	ns
Receiver enabled to output low					tRZL				2,8		20	120	ns
Receiver enables high output					tRZH CL=100pF,S2 Turn off			off Figure 2,8			20	120	ns
Receiver switches from high output to off Receiver switches from low output to off					tRHZ						20	120	ns
Chip shutdown time					tRLZ	CL=100pF		ıı rıgurez	.,0	50	200	120 600	ns
From chip off to driver enabled to output high					SHDN H(SH DN)	CI =15nF	S2 Turn o	ff Figure4	6	30		4500	ns ns
From chip off to driver enabled to ou					(SH DN)	CL=15pF.	S1 Turn o	ff Figure4	,6			4500 4500	ns
From chip off to driver enabled to ou					(SH DN)	CL=100pF						3500	ns
From chip off to driver enabled to ou		L(SH DN)	CL=100pF						3500				

- Δ VOD and Δ VOC respectively represent the changes in VOD and VOC when DI changes.
 The current is positive when flowing in and negative when flowing out. Unless noted, all voltages are referenced to ground.
 WhenRomoEo=1 and DE=0 , SN3485 enters the OFF state. If the duration of the off state is less than 50ns, the chip will n ot enter the off state. If the duration of the off state exceeds 600ns, the chip must enter the off state.

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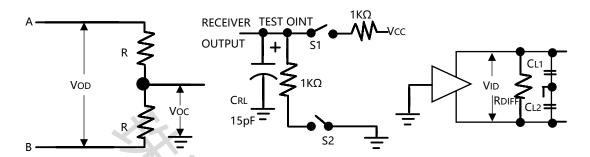


Figure 1 Driver DC characteristic test load

Figure 2 Receiver enable/Off switch characteristic test load

Figure 3. Actuator switch characteristic test circuit

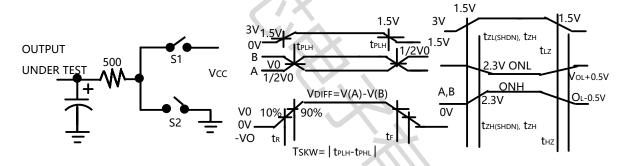


Figure 4 Driver enable/Off switch characteristic test load

Figure 5 Driver transmission delay Figure 6 Drive enable/disable sequence

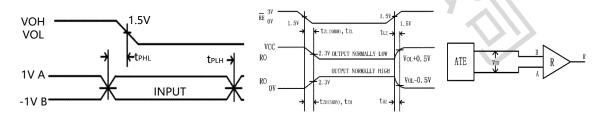


Figure 7 Receiver transmission delay

Figure 8 Receiver on/Off sequence

Figure 9 Receiver transmission delay test electrical

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Function Description

Bus Loading

The HX3078-S chip supports up to 256 transceivers on the same bus. A standard RS-485 receiver has an input impedance of 12K (1 unit load), while the HX3078-S features an input impedance of 96K (1/8 unit load). This allows for a total of 256 transceivers on the same bus. These devices can be used in any combination, including with other RS-485 transceivers, as long as the total load does not exceed 32 unit loads on the same bus.

Low power off mode

When RE is at high level and DE is at low level, the chip enters low-power shutdown mode. The typic al value of turn off current is 1.8uA. RE and DE can be driven simultaneously. If RE is at a high level a nd DE is at a low level for less than 50ns, the chip will not enter shutdown mode; If the holding time exceeds 600ns, the chip will ensure to enter the shutdown mode.

Reduce EMI and reflection

The limited swing rate driver of HX3078-S can reduce electromagnetic interference (EMI) and minimize reflections caused by improper terminal matching cables, achieving error free data transmission of up to 15Mbps.

Driver output protection

HX3078-S includes overcurrent and overpower protection mechanisms. The overcurrent protection circuit activates when excessive current occurs due to bus abnormalities, preventing the driving current from exceeding a preset limit. Additionally, the overtemperature protection circuit safeguards the chip by ensuring it remains undamaged during high power consumption and rising temperatures. If activated, this mode transitions the driver output to a high-resistance state.

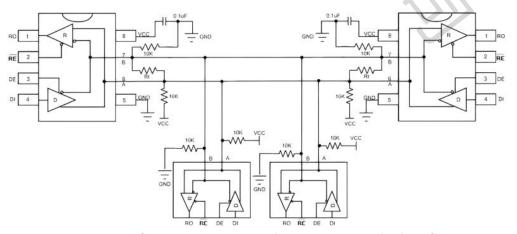
Typical applications

The HX3078-S is often used in multipoint networks for two-way communication. To minimize reflection, it's crucial to match its characteristic impedance at both ends of the transmission line, and keep the branch line length outside the main trunk as short as possible.

Electrostatic protection

The HX3078-S features ESD protection circuits on all pins to prevent damage during manual handling or assembly. Its driver and receiver pins have enhanced ESD circuits that can endure $\pm 15 \text{kV}$ human-mode ESD shocks without harm. These circuits are inactive during normal operation, avoiding current consumption. Post ESD, the chip operates flawlessly without latch-up or damage. Testing includes $\pm 15 \text{kV}$ human body model and $\pm 12 \text{kV}$ IEC61000-4-2 contact discharge methods.

Typical Application Diagram



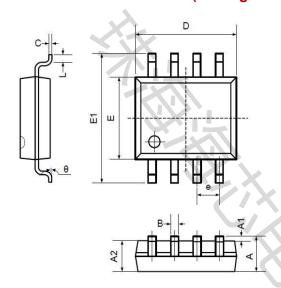
Rt is the feature matching impedance with a typical value of 120Ω

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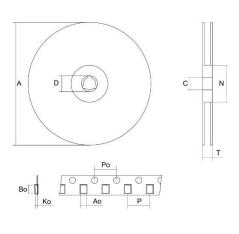
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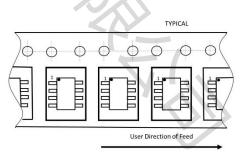
Packaging and packaging

SOP8 (Package Outline Dimensions)



Symbol		nsions meters	Dimensions In Inches			
	Min	Max	Min	Max		
Α	1.350	1.750	0.053	0.069		
A1	0.100	0.250	0.004	0.010		
A2	1.350	1.550	0.053	0.061		
В	0.330	0.510	0.013	0.020		
С	0.190	0.250	0.007	0.010		
D	4.780	5.000	0.188	0.197		
E	3.800	4.000	0.150	0.157		
E1	5.800	6.300	0.228	0.248		
е	1.270	TYP	0.050TYP			
L 0.400		1.270	0.016	0.050		
θ	0°	8°	0°	8°		





Packaging method	Number				
Braid	2500PCS/disk				

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